Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

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Notice

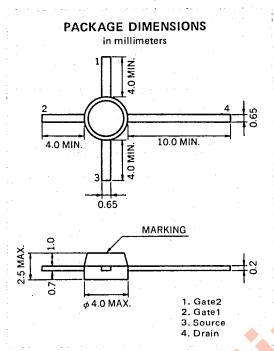
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MES FIELD EFFECT TRANSISTOR

3SK205

RF AMP. FOR UHF TV TUNER N-CHANNEL GaAs DUAL GATE MES FIELD-EFFECT TRANSISTOR 4PIN MINI MOLD



FEATURES

Suitable for use as RF amplifier in UHF TV tuner.

Low C_{rss}: 0.02 pF TYP.
 High G_{PS}: 20 dB TYP.
 Low NF: 1.1 dB TYP.

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Drain to Source Voltage	V_{DSX}	10	V	
Gate1 to Source Voltage	V_{G1S}	-4.5	V	
Gate2 to Source Voltage	V _{G2S}	-4.5	V	
Drain Current	ID	80	mA	
Total Power Dissipation	PT	200	mW	
Channel Temperature	T _{ch}	125	°C	
Storage Temperature	T_{stg}	-55 to +125	°C	

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

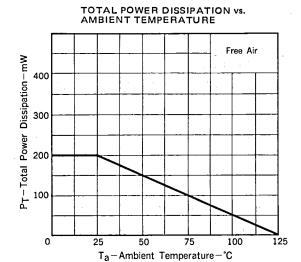
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS	
Drain to Source Breakdown Voltage	BVDSX	10			٧	$V_{G1S} = -4 V$, $V_{G2S} = 0$, $I_D = 20 \mu A$	
Drain Current	IDSS	10		80	mA	V _{DS} = 5 V, V _{G1S} = 0, V _{G2S} = 0	
Gate1 to Source Cutoff Voltage	VG1S(off)			-3.5	V	$V_{DS} = 5 \text{ V}, V_{G2S} = 0, I_D = 100 \mu A$	
Gate2 to Source Cutoff Voltage	VG2S(off)			-3.5	V	$V_{DS} = 5 V$, $V_{G1S} = 0$, $I_{D} = 100 \mu A$	
Gate1 Reverse Current	IG1SS			10	μΑ	V _{DS} = 0, V _{G1S} = -4 V, V _{G2S} = 0	
Gate2 Reverse Current	IG2SS			10	μΑ	V _{DS} = 0, V _{G2S} = -4 V, V _{G1S} = 0	
Forward Transfer Admittance	lyfsl	25	35		mS	V _{DS} = 5 V, V _{G2S} = 1 V, I _D = 10 mA f = 1.0 kHz	
Input Capacitance	Ciss	1.0	1.5	2.0	pF	V _{DS} = 5 V, V _{G2S} = 1 V, I _D = 10 mA,	
Reverse Transfer Capacitance	Crss		0.02	0.035	pF	f = 1.0 MHz	
Power Gain	GPS	16.0	20.0		dB	V _{DS} = 5 V, V _{G2S} = 1 V, I _D = 10 mA, f = 900 MHz	
Noise Figure	NF		1.1	2.5	dB		

IDSS Classification (Unit: mA)

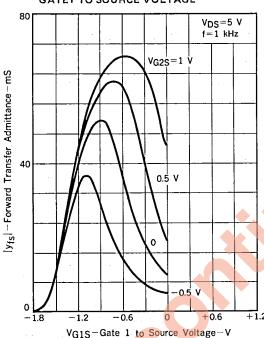
Marking	N	M	L	к	
IDSS	10 to 25	20 to 35	30 to 50	45 to 80	

PRECAUTION: Avoid high static voltages or electric fields so that this device would not suffer from any damage due to those voltage or fields.

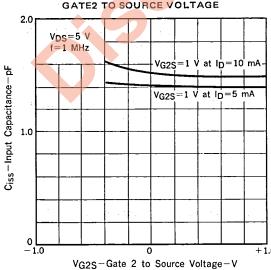
TYPICAL CHARACTERISTICS (Ta = 25°C)



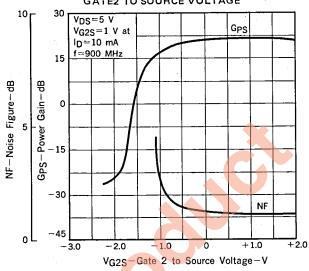
FORWARD TRANSFER ADMITTANCE vs. GATE1 TO SOURCE VOLTAGE



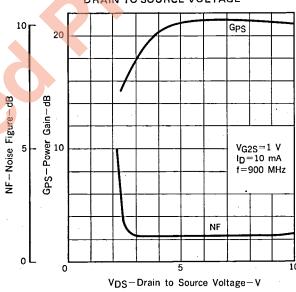
INPUT CAPACITANCE vs. GATE2 TO SOURCE VOLTAGE

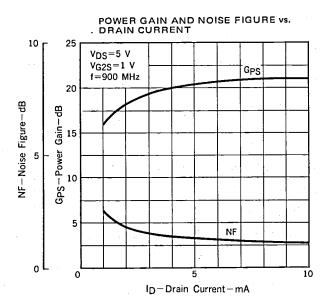


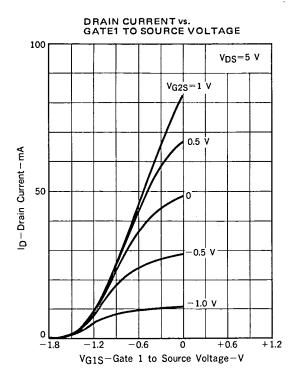
POWER GAIN AND NOISE FIGURE vs. GATE2 TO SOURCE VOLTAGE

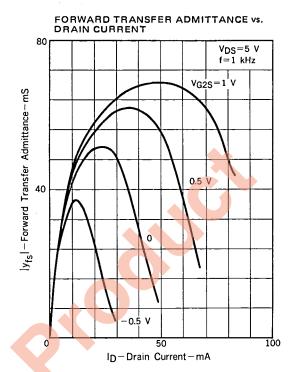


POWER GAIN AND NOISE FIGURE vs. DRAIN TO SOURCE VOLTAGE









S-PARAMETER ($V_{DS} = 5 \text{ V}$, $V_{G2S} = 1 \text{ V}$, $I_D = 10 \text{ mA}$)

FREQUENCY	;	S ₁₁	S	21	S	12	S	22
(MHz)	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100.00	1.006	-4.1	4.218	174.4	0.004	97.3	0.957	-2.2
200.00	0.979	-9.6	4.253	162.2	0.002	11.1	0.944	-4 .7
300.00	0.973	-12.4	4.065	156.2	0.005	82.6	0.954	-6.0
400.00	0.939	-18.2	3.944	148.2	0.007	92.1	0.952	-9.4
500.00	0.902	-19.7	3.854	145.7	0.005	79.3	0.944	-9.9
600.00	0.879	-26.0	4.068	135.0	0.007	68.6	0.963	-14.4
700.00	0.815	-26.8	3.734	127.2	0.006	95.3	0.938	-14.1
800.00	0.805	-31.9	3.727	120.3	0.009	92.8	0.958	-18.3
900.00	0.747	-33.0	3.586	115.4	0.007	109.8	0.939	-19.5
1000.00	0.743	-36.3	3.770	108.8	0.009	140.9	0.988	-23.4
1100.00	0.678	-36.7	3.574	99.4	0.007	172.7	0.955	-24.9
1200.00	0.703	-37.4	3.573	93.9	0.012	-147.6	1.040	-27.8

900 MHz G_{PS} AND NF TEST CIRCUIT

